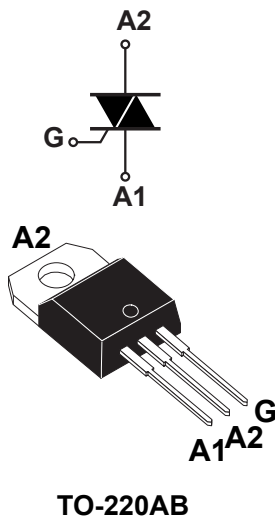


## 6 A 800 V logic level Triac in TO-220AB package



### Features

- Medium current Triac
- Three quadrants
- ECOPACK2 compliant

### Applications

- General purpose AC line load switching
- Motor control circuits
- Small home appliances
- Lighting
- Inrush current limiting circuits
- Overvoltage crowbar protection

### Description

Available in through-hole package, the T610T-8T Triac can be used for the on/off or phase angle control function in general purpose AC switching.

This device can be directly driven by a microcontroller due to its 10 mA gate current requirement.

#### Product status link

[T610T-8T](#)

#### Product summary

Order code	T610T-8T
Package	TO-220AB
$I_{T(RMS)}$	6 A
$V_{DRM}/V_{RRM}$	800 V
$V_{DSM}/V_{RSM}$	900 V
$I_{GT}$	10 mA

# 1 Characteristics

**Table 1. Absolute maximum ratings (limiting values)**

Symbol	Parameter		Value	Unit	
$I_{T(RMS)}$	On-state RMS current (full sine wave)		$T_c = 135\text{ °C}$	6	A
$I_{TSM}$	Non repetitive surge peak on-state current ( $T_j$ initial = 25 °C)	F = 50 Hz	t = 20 ms	45	A
		F = 60 Hz	t = 16.7 ms	47	
$I^2t$	$I^2t$ value for fusing, ( $T_j$ initial = 25 °C)		$t_p = 10\text{ ms}$	13	A <sup>2</sup> s
$V_{DRM}/V_{RRM}$	Repetitive surge peak off-state voltage		$T_j = 150\text{ °C}$	600	V
			$T_j = 125\text{ °C}$	800	
$V_{DSM}/V_{RSM}$	Non repetitive surge peak off-state voltage		$t_p = 10\text{ ms}$	900	V
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , tr ≤ 100 ns		F = 100 Hz	100	A/μs
$I_{GM}$	Peak gate current	$t_p = 20\text{ μs}$	$T_j = 150\text{ °C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ °C}$	1	W
$T_{stg}$	Storage junction temperature range			-40 to +150	°C
$T_j$	Operating junction temperature range			-40 to +150	°C
$T_L$	Maximum lead temperature soldering during 10 s			260	°C

**Table 2. Electrical characteristics ( $T_j = 25\text{ °C}$  unless otherwise specified)**

Symbol	Test conditions		Value	Unit	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$ , $R_L = 30\text{ Ω}$	I - II - III	Min.	0.5	mA
			Max.	10	
$V_{GT}$	$V_D = 12\text{ V}$ , $R_L = 30\text{ Ω}$	I - II - III	Max.	1.3	V
$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 3.3\text{ kΩ}$ , $T_j = 150\text{ °C}$	I - II - III	Min.	0.2	V
$I_H^{(1)}$	$I_T = 500\text{ mA}$		Max.	15	mA
$I_L$	$I_G = 1.2 \times I_{GT}$	I - III	Max.	20	mA
		II		25	
dV/dt <sup>(1)</sup>	$V_D = 536\text{ V}$ , gate open	$T_j = 125\text{ °C}$	Min.	250	V/μs
	$V_D = 402\text{ V}$ , gate open	$T_j = 150\text{ °C}$		170	
(di/dt) <sup>(1)</sup>	(dV/dt) <sub>c</sub> = 0.1 V/μs	$T_j = 125\text{ °C}$	Min.	5.2	A/ms
		$T_j = 150\text{ °C}$		3.7	
	(dV/dt) <sub>c</sub> = 10 V/μs	$T_j = 125\text{ °C}$		2.7	
		$T_j = 150\text{ °C}$		1.2	

1. For both polarities of A2 referenced to A1

**Table 3. Static characteristics**

Symbol	Test conditions			Value	Unit
$V_T^{(1)}$	$I_{TM} = 8.5 \text{ A}$ , $t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.55	V
$V_{TO}^{(1)}$	Threshold voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	0.85	
$R_d^{(1)}$	Dynamic resistance	$T_j = 150 \text{ }^\circ\text{C}$	Max.	75	m $\Omega$
$I_{DRM}$ , $I_{RRM}$	$V_D = V_R = 800 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	$\mu\text{A}$
		$T_j = 125 \text{ }^\circ\text{C}$		0.6	mA
	$V_D = V_R = 600 \text{ V}$	$T_j = 150 \text{ }^\circ\text{C}$	Max.	2.0	

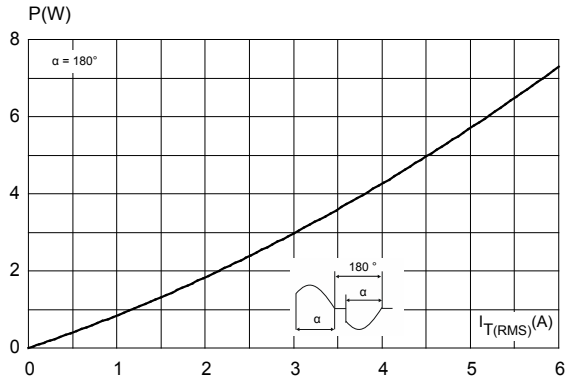
1. For both polarities of A2 referenced to A1

**Table 4. Thermal parameters**

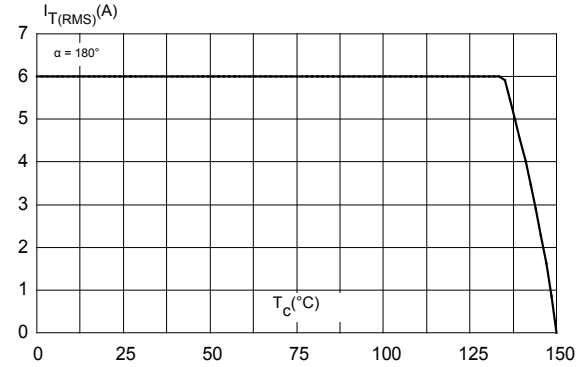
Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	2.1	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient	60	$^\circ\text{C/W}$

### 1.1 Characteristics curves

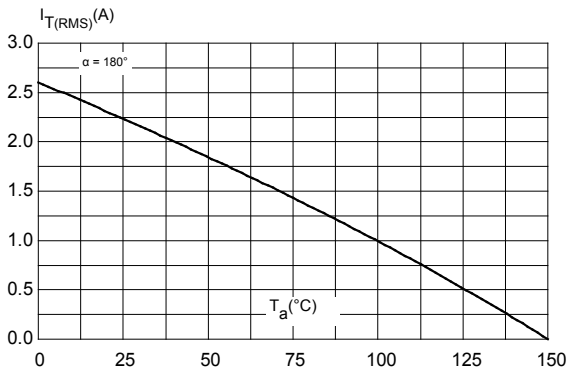
**Figure 1. Maximum power dissipation versus on-state RMS current**



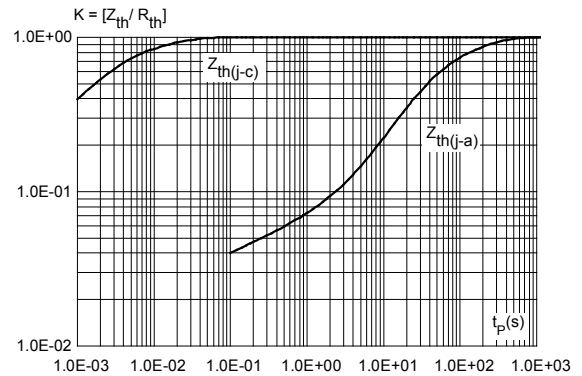
**Figure 2. On-state RMS current versus case temperature**



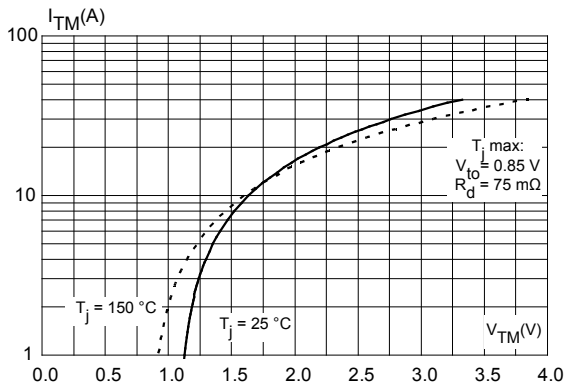
**Figure 3. On-state RMS current versus ambient temperature (free air convection)**



**Figure 4. Relative variation of thermal impedance versus pulse duration**



**Figure 5. On-state characteristics (maximum values)**



**Figure 6. Surge peak on-state current versus number of cycles**

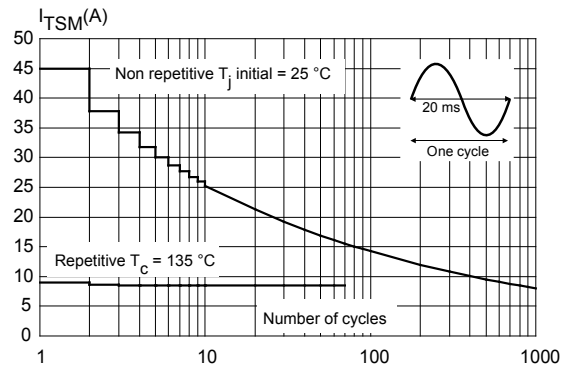


Figure 7. Non repetitive surge peak on-state current

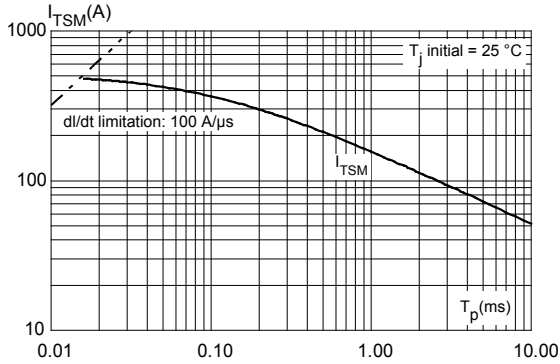


Figure 8. Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

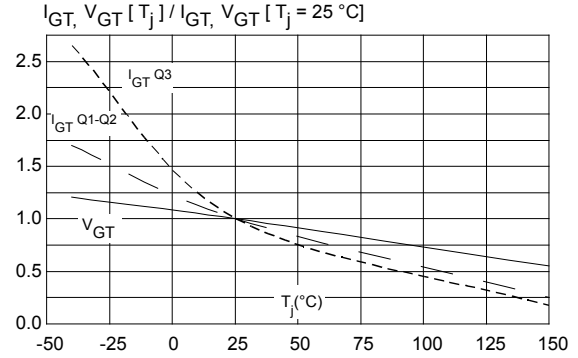


Figure 9. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus junction temperature (typical values)

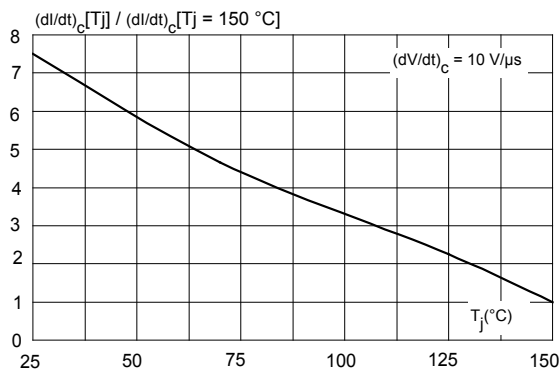


Figure 10. Relative variation of holding current and latching current versus junction temperature (typical values)

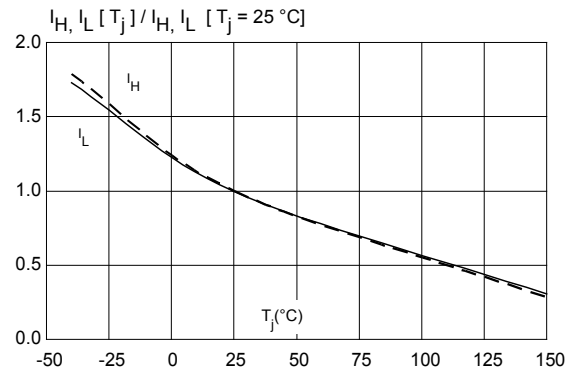


Figure 11. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus reapplied  $(dV/dt)_c$  (maximum values)

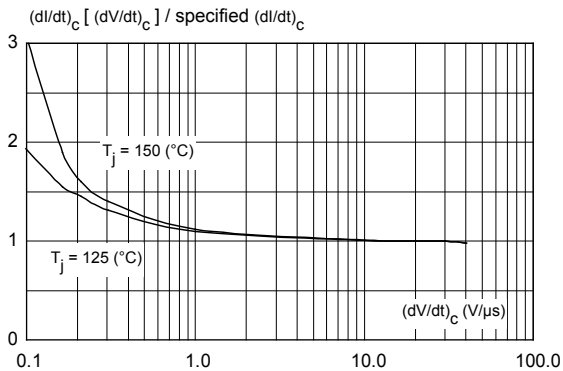


Figure 12. Relative variation of static  $dV/dt$  immunity versus junction temperature (typical values)

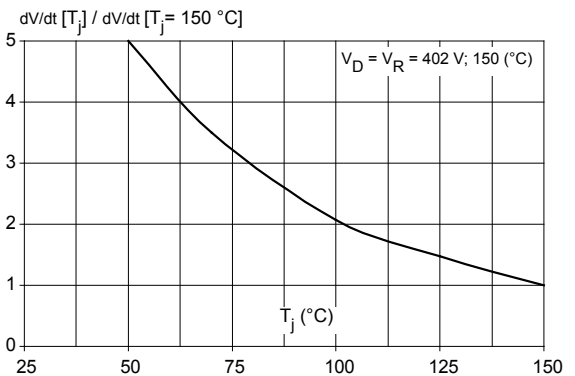
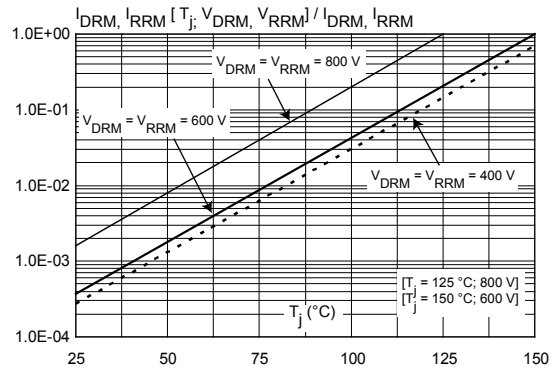


Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)



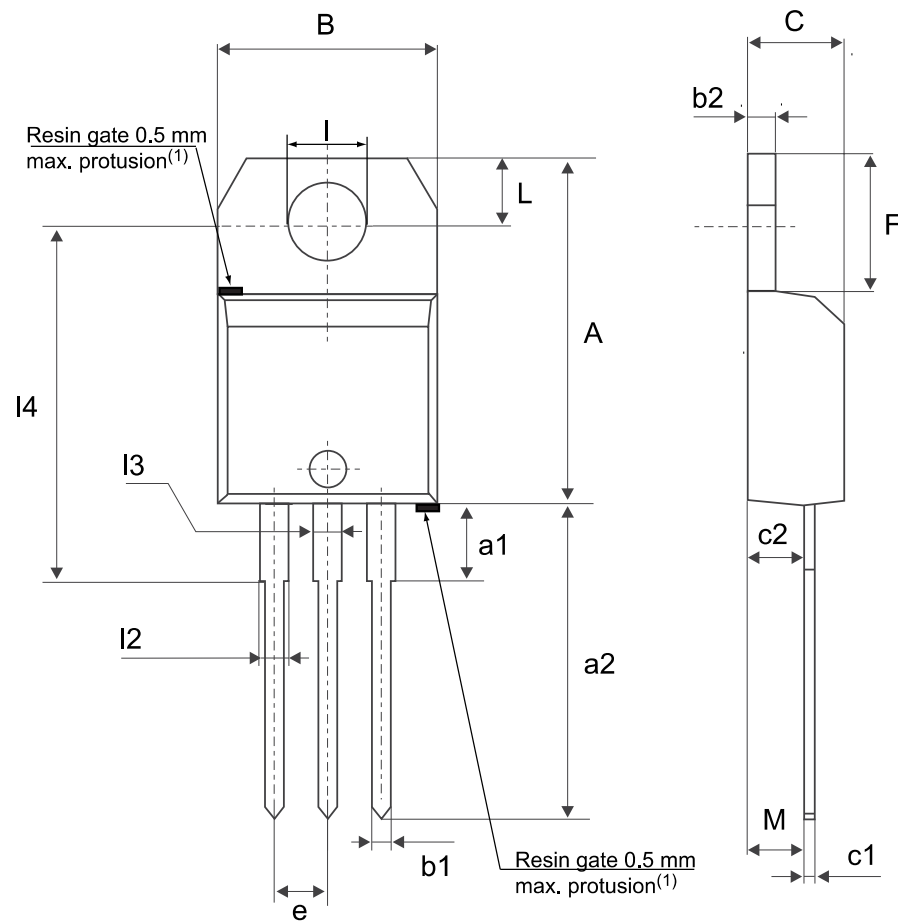
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 2.1 TO-220AB package information

- Epoxy resin is halogen free and meets UL94 flammability standard, level V0
- Lead-free plating package leads
- Recommended torque: 0.4 to 0.6 N·m

Figure 14. TO-220AB package outline



(1) Resin gate position accepted in one of the two positions or in the symmetrical opposites.

**Table 5. TO-220AB package mechanical data**

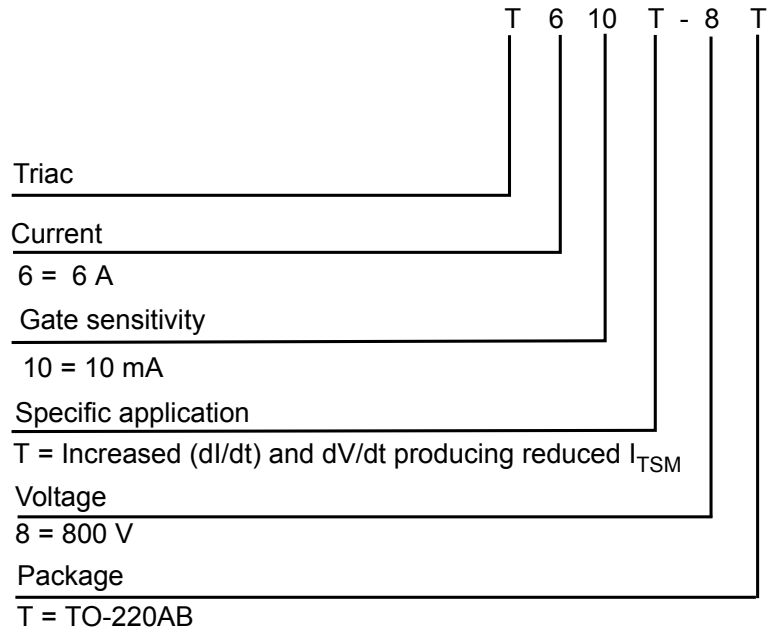
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
I2	1.14		1.70	0.0449		0.0669
I3	1.14		1.70	0.0449		0.0669
I4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. Inch dimensions are for reference only.



### 3 Ordering information

**Figure 15. Ordering information scheme**



**Table 6. Ordering information**

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T610T-8T	T610T-8T	TO-220AB	2.0 g	50	Tube

## Revision history

**Table 7. Document revision history**

Date	Revision	Changes
07-Nov-2014	1	Initial release.
13-Sep-2019	2	Updated <a href="#">Figure 14</a> and <a href="#">Table 5</a> .

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